

MC33762

Product Preview

Dual Ultra Low-Noise Low Dropout Voltage Regulator with 1V ON/OFF Control

The MC33762 is a dual Low DropOut (LDO) regulator featuring excellent noise performances. Thanks to its innovative concept, the circuit reaches an incredible $40\mu\text{VRMS}$ noise level *without* an external bypass capacitor. Housed in a small $\mu 8$ package, it represents the ideal designer's choice when space and noise are at premium.

The absence of external bandgap capacitor unleashes the response time to a wake-up signal and makes it stay within $40\mu\text{s}$, pushing the MC33762 as a natural candidate in portable applications.

The MC33762 also hosts a novel architecture which prevents excessive undershoots when the regulator is the seat of fast transient bursts, as in any bursting systems.

Finally, with a static line regulation better than -75dB , it naturally shields the downstream electronics against choppy lines.

Features

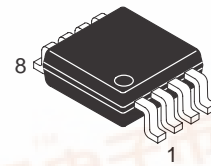
- Nominal output current of 80mA with a 100mA peak capability
- Ultra low-noise: $150\text{nV}/\sqrt{\text{Hz}}$ @ 100Hz, $40\mu\text{VRMS}$ 100Hz – 100kHz typical, $I_{\text{out}} = 60\text{mA}$, $C_{\text{o}} = 1\mu\text{F}$
- Fast response time from OFF to ON: $40\mu\text{s}$ typical
- Ready for 1V platforms: ON with a 900mV high level
- Typical dropout of 90mV @ 30mA, 160mV @ 80mA
- Ripple rejection: 70dB @ 1kHz
- 1.5% output precision @ 25°C
- Thermal shutdown
- Vout available from 2.5V to 5.0V

Applications

- Noise sensitive circuits: VCOs RF stages etc.
- Bursting systems (TDMA phones)
- All battery operated devices

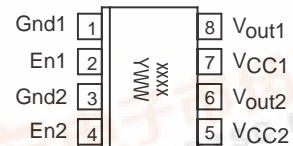


ON Semiconductor
Formerly a Division of Motorola
<http://onsemi.com>



Micro8
DM SUFFIX
CASE 846A

PIN CONFIGURATION AND MARKING DIAGRAM



xxxx = Version
YWW = Date Code
(Top View)

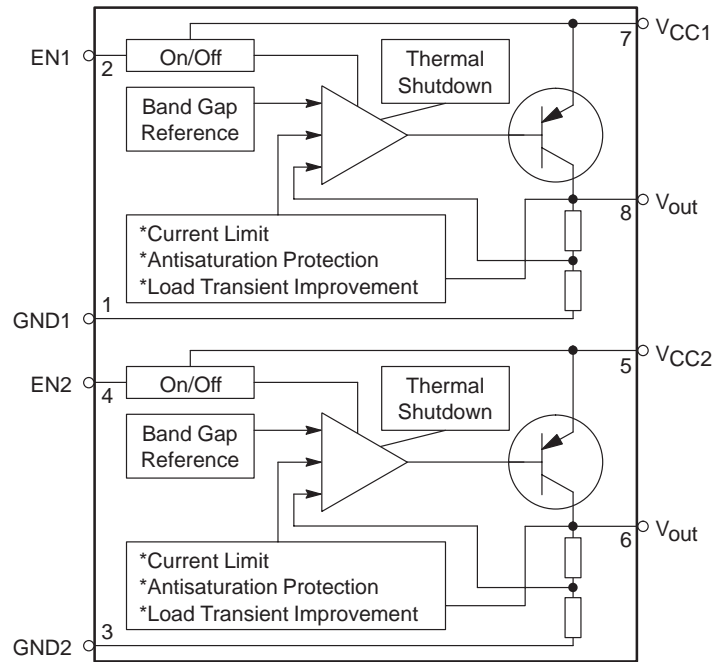
ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 11 of this data sheet.



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Simplified Block Diagram



PIN FUNCTION DESCRIPTIONS

Pin #	Pin Name	Function	Description
1	Gnd1	Ground of the 1st LDO	
2	En1	Enables the 1st LDO	A 900mV level on this pin is sufficient to start this LDO. A 150mV shuts it down.
3	Gnd2	Ground of the 2nd LDO	
4	En2	Enables the 2nd LDO	A 900mV level on this pin is sufficient to start this LDO. A 150mV shuts it down.
5	V _{cc2}	2nd LDO V _{cc} pin	This pin brings the power to the 1st LDO and requires adequate decoupling.
6	V _{out2}	Shuts or wakes-up the IC	This pin requires a 1μF output capacitor to be stable.
7	V _{cc1}	1st LDO V _{cc} pin	This pin brings the power to the 1st LDO and requires adequate decoupling.
8	V _{out1}	Delivers the output voltage	This pin requires a 1μF output capacitor to be stable.

MAXIMUM RATINGS

Rating	Pin #	Symbol	Value		Unit
			Min	Max	
Power Supply Voltage	1	V _{in}	—	12	V
ESD Capability, HBM Model	All Pins			1	kV
ESD Capability, Machine Model	All Pins			200	V
Maximum Power Dissipation NW Suffix, Plastic Package Thermal Resistance Junction-to-Air		P _D R _{θJ-A}		Internally Limited 240	W °C/W
Operating Ambient Temperature		T _A		-40 to +85	°C
Maximum Junction Temperature (1)		T _{Jmax}		150	°C
Maximum Operating Junction Temperature (2)		T _J		125	°C
Storage Temperature Range		T _{stg}		-60 to +150	°C

(1). Internally limited by shutdown.

(2). Specifications are guaranteed below this value.

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ELECTRICAL CHARACTERISTICS

(For Typical Values $T_A = 25^\circ\text{C}$, for Min/Max values $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$, Max $T_J = 125^\circ\text{C}$ unless otherwise noted)

Characteristics	Pin #	Symbol	Min	Typ	Max	Unit
Logic Control Specifications						
Input Voltage Range	2-4	$V_{ON/OFF}$	0		V_{in}	V
ON/OFF Input Resistance (all versions)	2-4	$R_{ON/OFF}$		250		k Ω
ON/OFF Control Voltages (3) Logic Zero, OFF State, $I_O = 50$ mA Logic One, ON State, $I_O = 50$ mA	2-4	$V_{ON/OFF}$	900		150	mV

Currents Parameters

Current Consumption in OFF State (all versions) OFF Mode Current: $V_{in} = V_{out} + 1$ V, $I_O = 0$, $V_{OFF} = 150$ mV		I_{QOFF}		0.1	2	μA
Current Consumption in ON State (all versions) ON Mode Current: $V_{in} = V_{out} + 1$ V, $I_O = 0$, $V_{ON} = 3.5$ V		I_{QON}		180		μA
Current Consumption in ON State (all versions), ON Mode Saturation Current: $V_{in} = V_{out} - 0.5$ V, No Output Load		I_{QSAT}		800		μA
Current Limit $V_{in} = V_{out_{nom}} + 1$ V, Output is brought to $V_{out_{nom}} - 0.3$ V (all versions)		I_{MAX}	100	180		mA

(3) Voltage Slope should be Greater than 2 mV/ μs

ELECTRICAL CHARACTERISTICS

(For Typical Values $T_A = 25^\circ\text{C}$, for Min/Max values $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$, Max $T_J = 125^\circ\text{C}$ unless otherwise noted)

Characteristics	Pin #	Symbol	Min	Typ	Max	Unit
Output Voltages						
$V_{out} + 1$ V < $V_{in} < 6$ V, $T_A = 25^\circ\text{C}$, 1 mA < $I_{out} < 80$ mA 2.5 V	5-7	V_{out}	2.462	2.5	2.537	V
2.8 V	5-7	V_{out}	2.758	2.8	2.842	V
3.0 V	5-7	V_{out}	2.955	3.0	3.045	V
3.3 V	5-7	V_{out}	3.250	3.3	3.349	V
3.6 V	5-7	V_{out}	3.546	3.6	3.654	V
Other Voltages up to 5V Available in 50mV Increments Steps	5-7	V_{out}	-1.5	X	+1.5	%
$V_{out} + 1$ V < $V_{in} < 6$ V, $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$, 1mA < $I_{out} < 80$ mA 2.5 V	5-7	V_{out}	2.425	2.5	2.575	V
2.8 V	5-7	V_{out}	2.716	2.8	2.884	V
3.0 V	5-7	V_{out}	2.91	3.0	3.090	V
3.3 V	5-7	V_{out}	3.201	3.3	3.399	V
3.6 V	5-7	V_{out}	3.492	3.6	3.708	V
Other Voltages up to 5V Available in 50mV Increments Steps	5-7	V_{out}	-3	X	+3	%

Line and Load Regulation, Dropout Voltages

Line Regulation (all versions) $V_{out} + 1$ V < $V_{in} < 12$ V, $I_{out} = 80$ mA	5-7	Reg _{line}			20	mV
Load Regulation (all versions) $V_{in} = V_{out} + 1$ V, $C_{out} = 1$ μF , $I_{out} = 1$ to 80 mA	5-7	Reg _{load}			40	mV
Dropout Voltage (all versions) (3) $I_{out} = 30$ mA $I_{out} = 60$ mA $I_{out} = 80$ mA	5-7 5-7 5-7	$V_{in}-V_{out}$ $V_{in}-V_{out}$ $V_{in}-V_{out}$		90 140 160	150 200 250	mV

Dynamic Parameters

Ripple Rejection (all versions) $V_{in} = V_{out} + 1$ V + 1 kHz 100 mVpp Sinusoidal Signal	5-7	Ripple		-70		dB
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Characteristics	Pin #	Symbol	Min	Typ	Max	Unit
Dynamic Parameters						
Output Noise Density @ 1 kHz	5-7			150		nV/ √Hz
RMS Output Noise Voltage (all versions) C _{out} = 1 μF, I _{out} = 50 mA, F = 100 Hz to 1 MHz	5-7	Noise		35		μV
Output Rise Time (all versions) C _{out} = 1 μF, I _{out} = 50 mA, 10% of Rising ON Signal to 90% of Nominal V _{out}	5-7	t _{rise}		40		μs

Thermal Shutdown

Thermal Shutdown (all versions)					125	°C
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(3) V_{out} is brought to V_{out} – 100 mV

DEFINITIONS

Load Regulation

The change in output voltage for a change in output current at a constant chip temperature.

Dropout Voltage

The input/output differential at which the regulator output no longer maintains regulation against further reductions in input voltage. Measured when the output drops 100mV below its nominal value (which is measured at 1V differential value). The dropout level is affected by the chip temperature, load current and minimum input supply requirements.

Output Noise Voltage

This is the integrated value of the output noise over a specified frequency range. Input voltage and output current are kept constant during the measurement. Results are expressed in μVRMS.

Maximum Power Dissipation

The maximum total dissipation for which the regulator will operate within its specs.

Quiescent Current

The quiescent current is the current which flows through the ground when the LDO operates without a load on its output: internal IC operation, bias etc. When the LDO becomes loaded, this term is called the Ground current. It is actually the difference between the input current (measured through the LDO input pin) and the output current.

Line Regulation

The change in output voltage for a change in input voltage. The measurement is made under conditions of low dissipation or by using pulse technique such that the average chip temperature is not significantly affected. One usually distinguishes *static line regulation* or *DC line regulation* (a DC step in the input voltage generates a corresponding step in the output voltage) from *ripple rejection* or *audio susceptibility* where the input is combined with a frequency generator to sweep from a few hertz up to a defined boundary while the output amplitude is monitored.

Thermal Protection

Internal thermal shutdown circuitry is provided to protect the integrated circuit in the event that the maximum junction temperature is exceeded. When activated at typically 125°C, the regulator turns off. This feature is provided to prevent catastrophic failures from accidental overheating.

Maximum Package Power Dissipation

The maximum power package power dissipation is the power dissipation level at which the junction temperature reaches its maximum operating value, i.e. 125°C. Depending on the ambient temperature, it is possible to calculate the maximum power dissipation and thus the maximum available output current.

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Characterization Curves

Curves are Common to Both Regulators

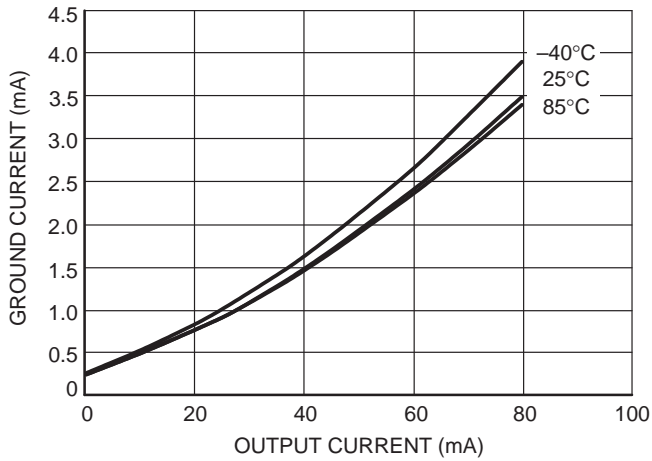


Figure 1. Ground Current versus Output Current

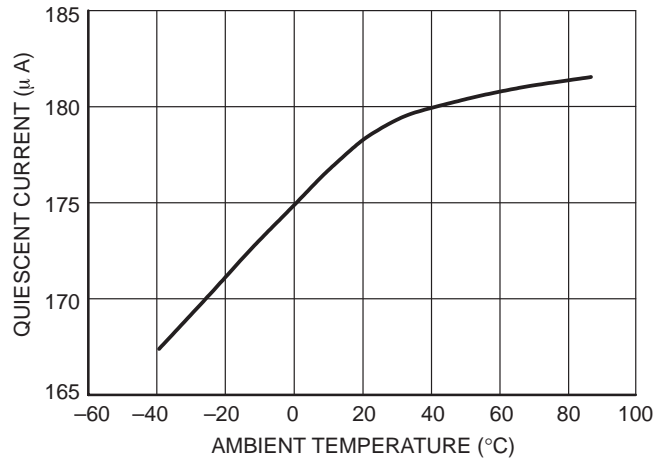


Figure 2. Quiescent Current versus Temperature

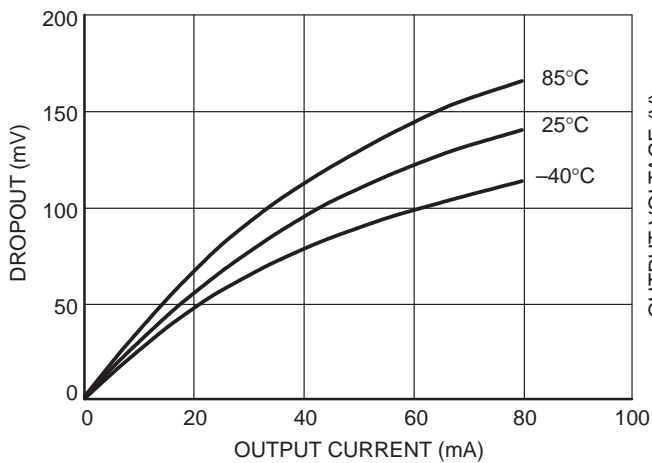


Figure 3. Dropout versus Output Current

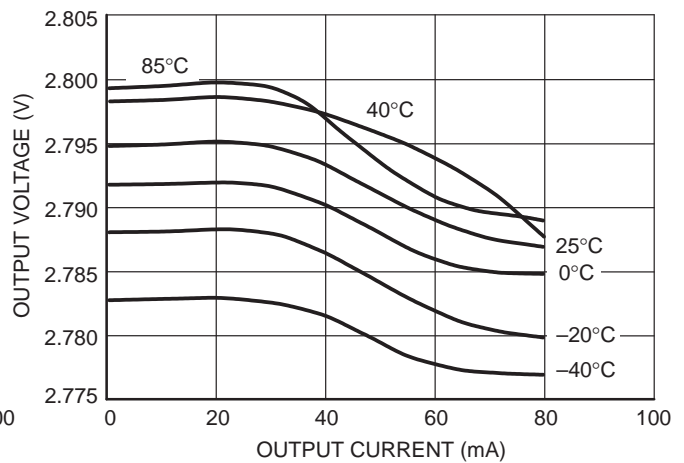


Figure 4. Output Voltage versus Output Current

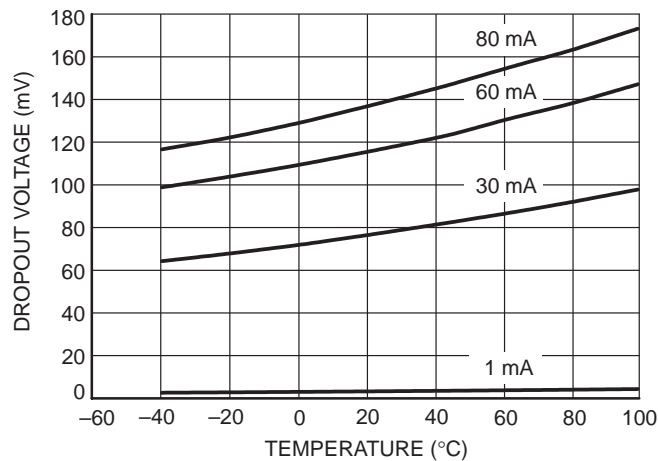


Figure 5. Dropout versus Temperature

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APPLICATION HINTS

Input Decoupling

As with any regulator, it is necessary to reduce the dynamic impedance of the supply rail that feeds the component. A 1µF capacitor either ceramic or tantalum is recommended and should be connected close to the MC33762 package. Higher values will correspondingly improve the overall line transient response.

Output Decoupling

Thanks to a novel concept, the MC33762 is a stable component and does not require any specific Equivalent Series Resistance (ESR) neither a minimum output current. Capacitors exhibiting ESRs ranging from a few mΩ up to 3Ω can thus safely be used. The minimum decoupling value is 1µF and can be augmented to fulfill stringent load transient requirements. The regulator accepts ceramic chip capacitors as well as tantalum devices.

Noise Performances

Unlike other LDOs, the MC33762 is a true low-noise regulator. Without the need of an external bypass capacitor, it typically reaches the incredible level of 40µVRMS overall noise between 100 Hz and 100 kHz. To give maximum insight on noise specifications, ON Semiconductor includes spectral density graphics. The classical bypass capacitor impacts the start-up phase of standard LDOs. However, thanks to its low-noise architecture, the MC33762 operates without a bypass element and thus offers a typical 40µs start-up phase.

Protections

The MC33762 hosts several protections, giving natural ruggedness and reliability to the products implementing the

component. The output current is internally limited to a maximum value of 180 mA *typical* while temperature shutdown occurs if the die heats up beyond 125°C. These values let you assess the maximum differential voltage the device can sustain at a given output current before its protections come into play.

The maximum dissipation the package can handle is given by:

$$P_{\max} = \frac{T_{J\max} - T_A}{R_{\theta JA}}$$

If $T_{J\max}$ is limited to 125°C, then the MC33762 can dissipate up to 395mW @ 25°C. The power dissipated by the MC33762 can be calculated from the following formula:

$$P_{\text{tot}} = (V_{\text{in}} \times I_{\text{gnd}}(I_{\text{out}})) + (V_{\text{in}} - V_{\text{out}}) \times I_{\text{out}}$$

or

$$V_{\text{in}\max} = \frac{P_{\text{tot}} + V_{\text{out}} \times I_{\text{out}}}{I_{\text{gnd}} + I_{\text{out}}}$$

If a 80mA output current is needed, the ground current is extracted from the data-sheet curves: 4mA @ 80mA. For a half 2.8V MC33762 (2.8 V) operating at 25°C, the maximum input voltage will then be 7.3V.

Typical Applications

The following picture portrays the typical application of the MC33762.

Figure 6.

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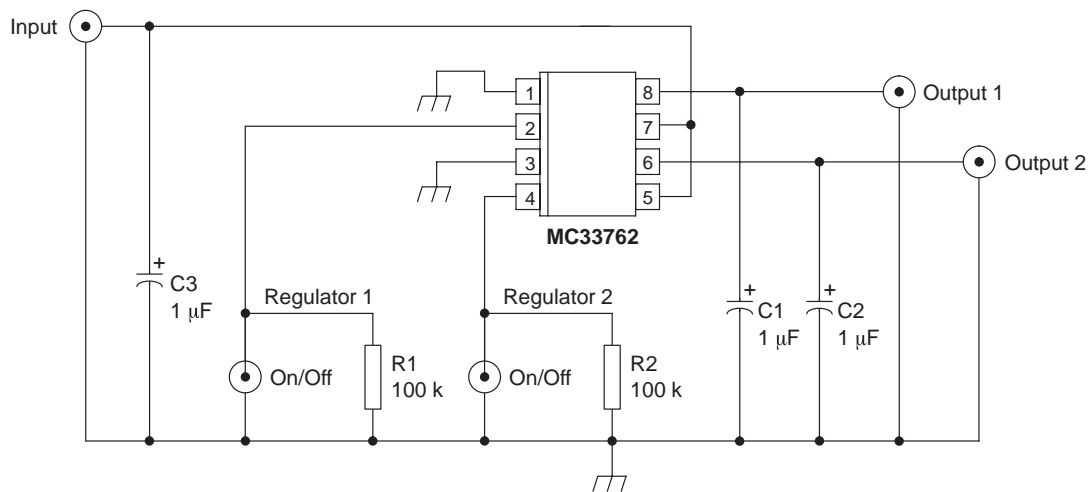


Figure 7. A Typical Application Schematic

As for any low noise designs, particular care has to be taken when tackling Printed Circuit Board (PCB) layout. Connections shall be kept short and wide. Layout example

as given in the MC33761 application hints can be used as a starting basis.

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Understanding the Load Transient Improvement

The MC33762 features a novel architecture which allows the user to easily implement the regulator in burst systems where the time between two current shots is kept very small.

The quality of the transient response time is related to many parameters, among which the closed-loop bandwidth with the corresponding phase margin plays an important role. However, other characteristics also come into play like the series pass transistor saturation. When a current perturbation suddenly appears on the output, e.g. a load increase, the error amplifier reacts and actively biases the PNP transistor. During this reaction time, the LDO is in open-loop and the output impedance is rather high. As a result, the voltage brutally drops until the error amplifier effectively closes the loop and corrects the output error. When the load disappears, the opposite phenomenon takes place with a positive overshoot. The problem appears when this overshoot decays down to the LDO steady-state value.

During this decreasing phase, the LDO stops the PNP bias and one can consider the LDO asleep (figure 8). If by misfortune a current shot appears, the reaction time is incredibly lengthened and a strong undershoot takes place. This reaction is clearly not acceptable for line sensitive devices, such as VCOs or other Radio-Frequency parts. This problem is dramatically exacerbated when the output current drops to zero rather than a few mA. In this later case, the internal feedback network is the only discharge path, accordingly lengthening the output voltage decay period (figure 9).

The MC33762 cures this problem by implementing a clever design where the LDO detects the presence of the overshoot and forces the system to go back to steady-state as soon as possible, ready for the next shot. Figure 10 and 11 show how it positively improves the response time and decreases the negative peak voltage.

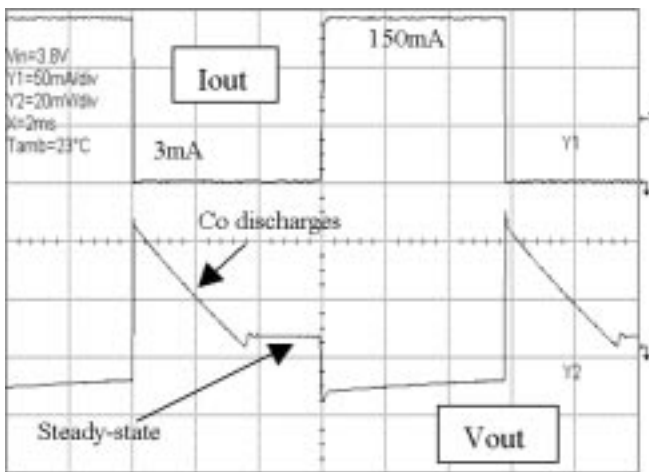


Figure 8. A standard LDO behavior when the load current disappears

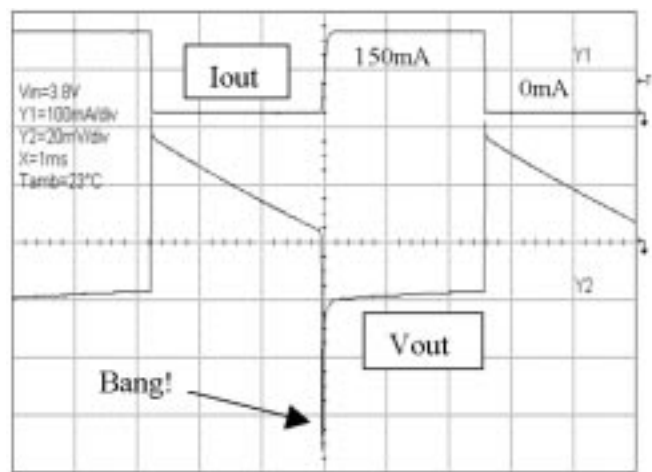


Figure 9. A standard LDO behavior when the load current appears in the decay zone

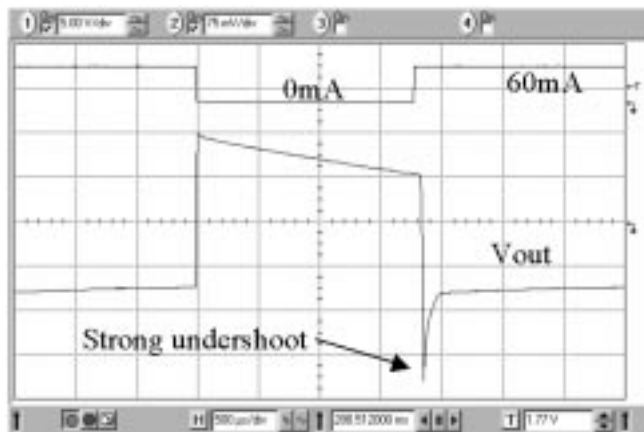


Figure 10. Without load transient improvement

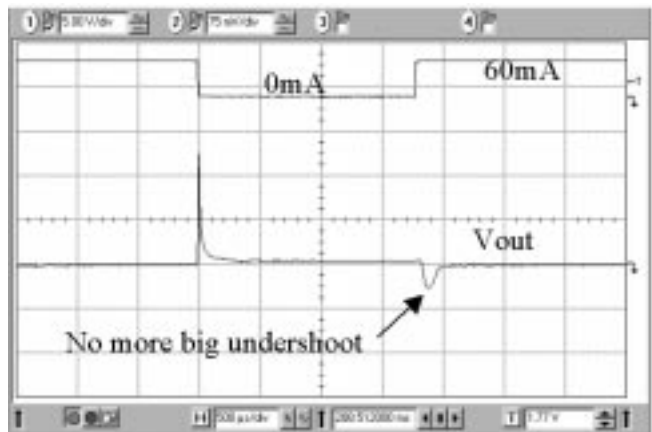


Figure 11. MC33762 with load transient improvement

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MC33762 has a fast start-up phase

Thanks to the lack of bypass capacitor the MC33762 is able to supply its downstream circuitry as soon as the OFF to ON signal appears. In a standard LDO, the charging time of the external bypass capacitor hampers the response time. A simple solution consists in suppressing this bypass element but, unfortunately, the noise rises to an

unacceptable level. MC33762 offers the best of both worlds since it no longer includes a bypass capacitor and starts in less than 40 μ s typically (Repetitive at 200Hz). It also ensures an incredible low-noise level of 40 μ VRMS 100Hz–100kHz. The following picture details the typical 33762 startup phase.

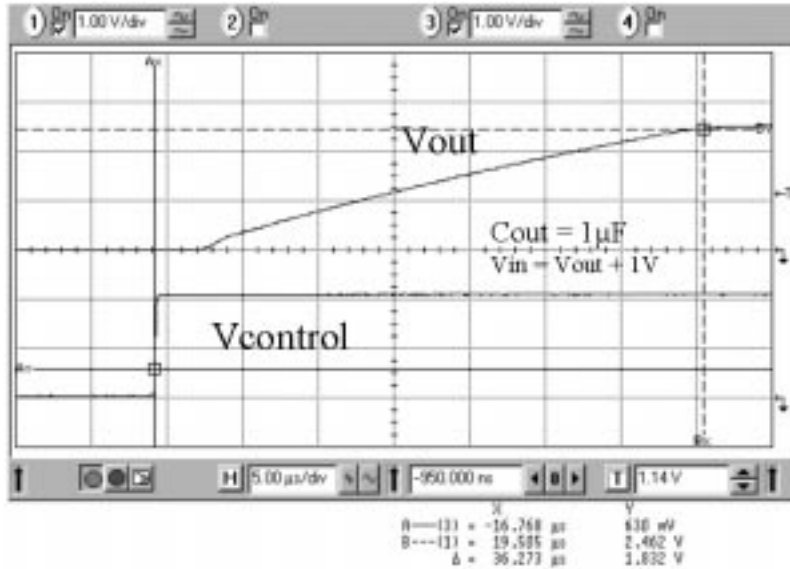


Figure 12. Repetitive start-up waveforms

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TYPICAL TRANSIENT RESPONSES

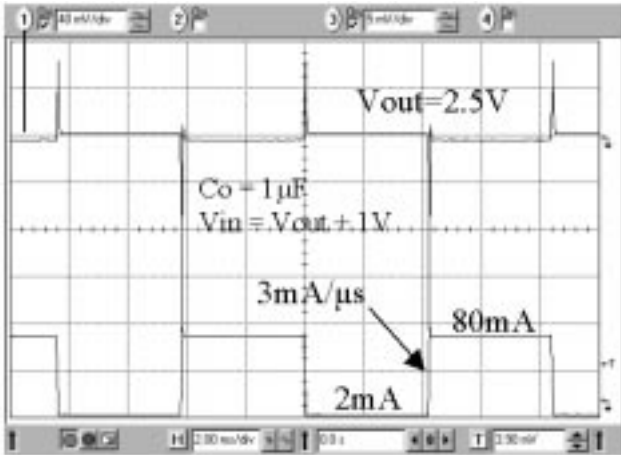


Figure 13. Output is pulsed from 2mA to 80mA

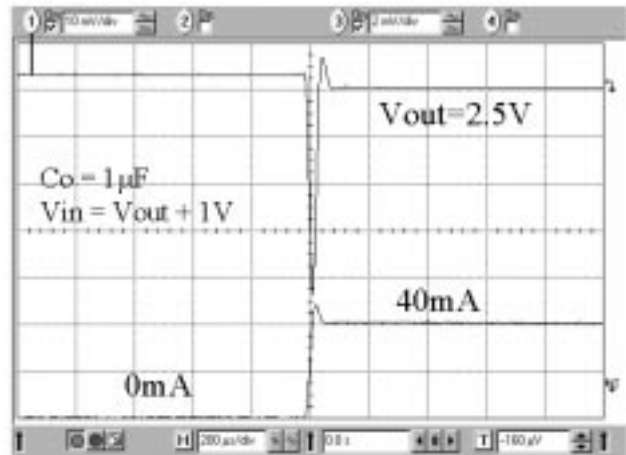


Figure 14. Discharge effects from 0 to 40mA

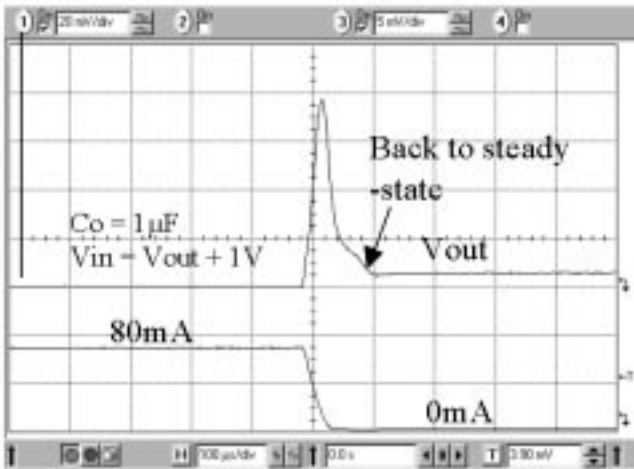


Figure 15. Load transient improvement effect

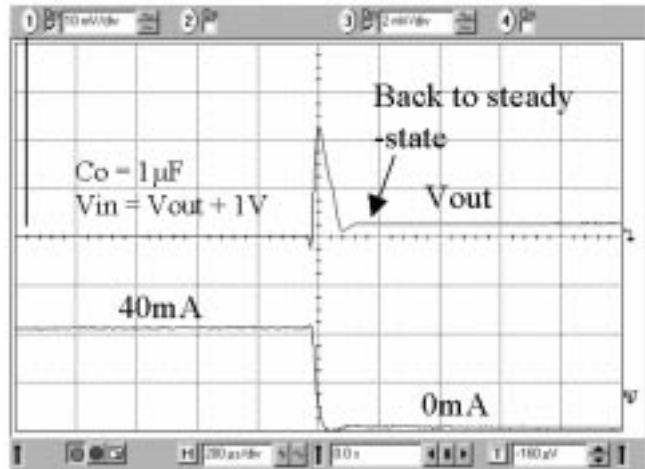


Figure 16. Load transient improvement effect

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TYPICAL TRANSIENT RESPONSES

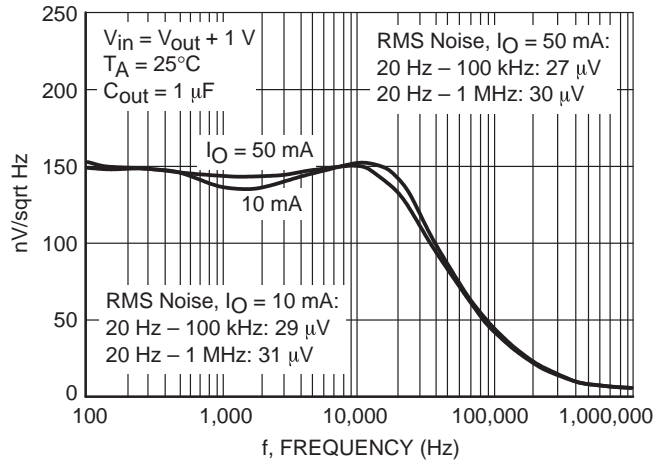


Figure 17. MC33762 Typical Noise Density Performance

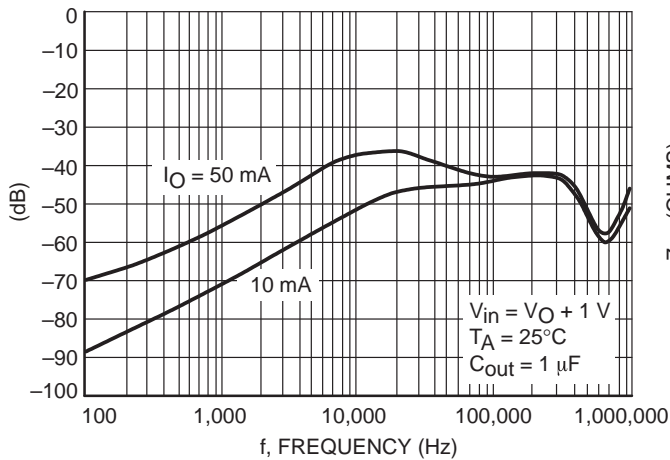


Figure 18. MC33762 Typical Ripple Rejection Performance

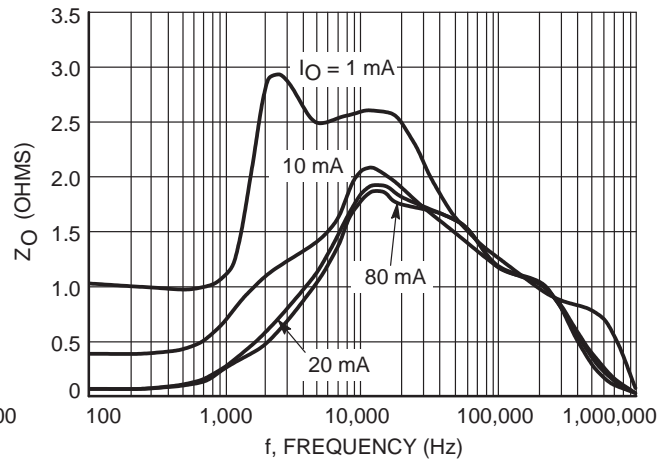


Figure 19. Output Impedance Plot
C_{out} = 1 μF, V_{in} = V_{out} + 1 V

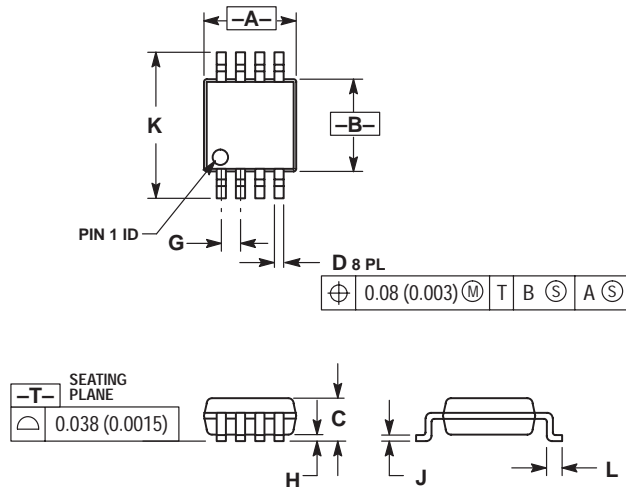
ORDERING INFORMATION

Part Number	Voltage Output	Package	Shipping
MC33762DM-2525R2	2.5V & 2.5V	Micro-8	4000 Units / Tape & Reel
MC33762DM-2828R2	2.8V & 2.8V	Micro-8	4000 Units / Tape & Reel
MC33762DM-3030R2	3.0V & 3.0V	Micro-8	4000 Units / Tape & Reel

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PACKAGE DIMENSIONS


Micro8
PLASTIC PACKAGE
CASE 846A-02
ISSUE D



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.90	3.10	0.114	0.122
B	2.90	3.10	0.114	0.122
C	---	1.10	---	0.043
D	0.25	0.40	0.010	0.016
G	0.65 BSC		0.026 BSC	
H	0.05	0.15	0.002	0.006
J	0.13	0.23	0.005	0.009
K	4.75	5.05	0.187	0.199
L	0.40	0.70	0.016	0.028

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